

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)			
30	0.023 at V _{GS} = 10 V	5.6	2.9 nC			
50	0.025 at V _{GS} = 4.5 V	4.6	2.9110			

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET

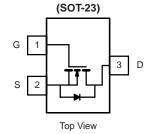
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- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

DC/DC Converter





S N-Channel MOSFET

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Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current (T _J = 150 °C)	$T_{C} = 25 °C$ $T_{C} = 70 °C$ $T_{A} = 25 °C$ $T_{A} = 70 °C$	- I _D -	5.6 ^a 4.3 3.3 2.7	A	
Pulsed Drain Current		I _{DM}	17		
Continuous Source-Drain Diode Current	T _C = 25 °C T _A = 25 °C	I _S	1.9 0.9 ^{b, c}		
Maximum Power Dissipation	$T_{C} = 25 °C$ $T_{C} = 70 °C$ $T_{A} = 25 °C$ $T_{A} = 70 °C$	P _D	1.8 1.2 1.1 ^{b, c} 0.7 ^{b, c}	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		
Soldering Recommendations (Peak Temperature) ^{d, e}			260	Ŭ	

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	90	119	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	60	78			

Notes:

a. Package limited

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 130 °C/W.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static						1	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = 250 \mu A$	30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	L 050 ··· A		31		- mV/°0	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = 250 μA		- 5			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.2		2.2	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α	
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.2 \text{ A}$	0.023 0.026		0.026		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_{D} = 2.8 \text{ A}$		0.025	0.028	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 4.8 A		12		S	
Dynamic ^b					•	1	
Input Capacitance	C _{iss}			275			
Output Capacitance	C _{oss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		47		pF	
Reverse Transfer Capacitance	C _{rss}			19			
Total Gate Charge	Qg	V_{DS} = 15 V, V_{GS} = 10 V, I_{D} = 3.4 A		4.5	6.7	nC	
				2.1	3.2		
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 3.4 A		0.85			
Gate-Drain Charge	Q _{gd}			0.65			
Gate Resistance	Rg	f = 1 MHz	0.8	4.4	8.8	Ω	
Turn-On Delay Time	t _{d(on)}			12	20		
Rise Time	t _r	V_{DD} = 15 V, R_L = 5.6 Ω		50	75		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ 2.7 A, V_GEN = 4.5 V, R_g = 1 Ω		12	20		
Fall Time	t _f			22	35		
Turn-On Delay Time	t _{d(on)}			5	10	ns	
Rise Time	t _r	V_{DD} = 15 V, R_L = 5.6 Ω		12	20	-	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}{\cong}2.7$ A, V_GEN = 10 V, R_g = 1 Ω		10	15		
Fall Time	t _f			5	10		
Drain-Source Body Diode Characteristi	cs			1	I		
Continuous Source-Drain Diode Current	۱ _S	$T_{C} = 25 \ ^{\circ}C$			1.9	^	
Pulse Diode Forward Current	I _{SM}				17	A	
Body Diode Voltage	V _{SD}	$I_{S} = 2.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			10	20	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = 2.7 A, dl/dt = 100 A/µs, T _{.1} = 25 °C		5	10	nC	
Reverse Recovery Fall Time	t _a	$F = 2.7 \text{ A}, \text{ unat} = 100 \text{ A/}\mu\text{s}, 1\text{ J} = 25 \text{ C}$		6			
Reverse Recovery Rise Time	t _b			4		ns	

Notes:

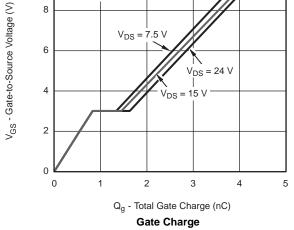
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 % b. Guaranteed by design, not subject to production testing.

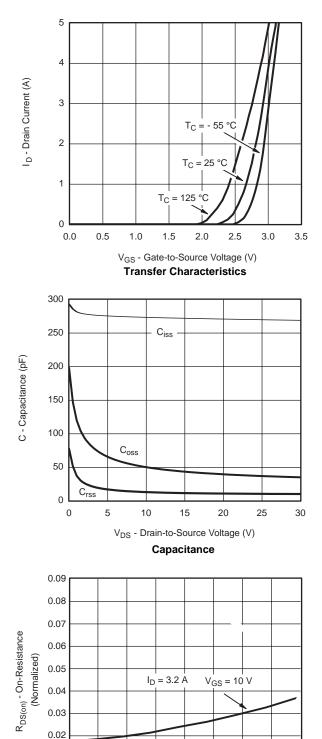
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

15 V_{GS} = 10 V thru 4 V 12 ID - Drain Current (A) 9 6 $V_{GS} = 3 V$ 3 0 0.5 2.5 3.0 0.0 1.0 1.5 2.0 V_{DS} - Drain-to-Source Voltage (V) **Output Characteristics** 0.06 0.05 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$ - On-Resistance ($\Omega)$ 0.04 0.03 V_{GS} = 4.5 V 0.02 V_{GS} = 10 V 0.00 0 3 6 9 12 15 I_D - Drain Current (A) **On-Resistance vs. Drain Current and Gate Voltage** 10 $I_{D} = 3.4 \text{ A}$ 8 V_{DS} = 7.5 V





0.01

0.00

- 50

- 25

0

25

50

T_J - Junction Temperature (°C) On-Resistance vs. Junction Temperature

75

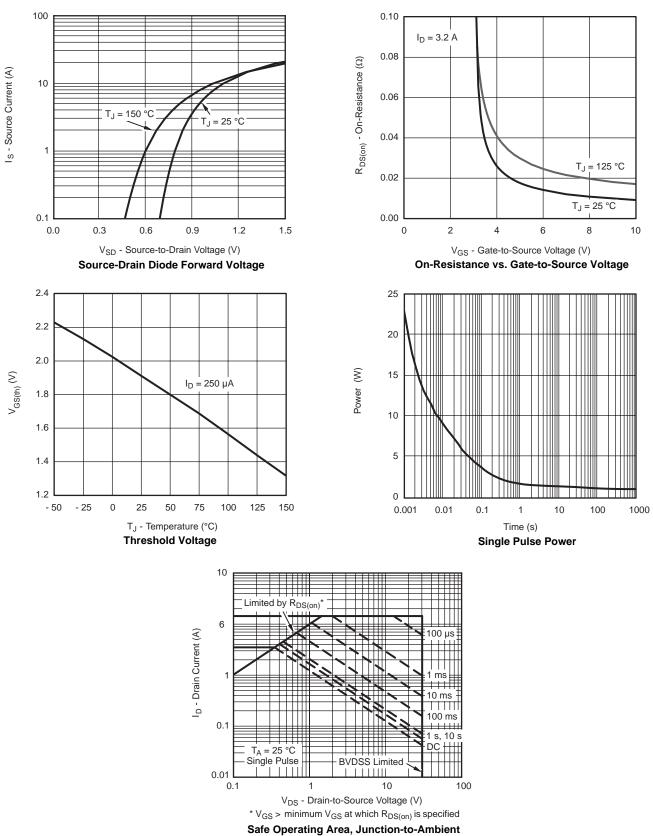
100

125 150

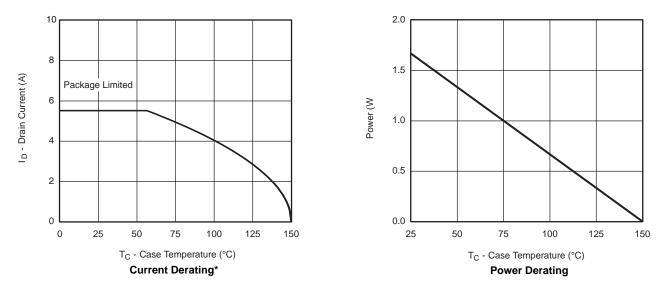
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



10⁻³

1 Duty Cycle = 0.5 +++Normalized Effective Transient Thermal Impedance 0.2 ТΙ ΠL 0.1 Notes 0.1 P_{DM} 0.05 t₁ Ш 0.02 t₂ t1 1. Duty Cycle, D = t₂ 2. Per Unit Base = $R_{thJA}^{t_2}$ = 130 °C/W 3. T_{JM} - $T_A = P_{DM}Z_{thJA}^{(t)}$ Single Pulse 4. Surface Mounted 0.01 10⁻⁴ 10⁻³ 10⁻² 10⁻¹ 1 10 100 1000 Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Ambient 1 Duty Cycle = 0.5 Normalized Effective Transient Thermal Impedance 0.2 0.1 0.1 0.05 +. 0.02 Single Pulse

Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Foot

10⁻²

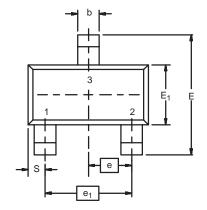
10⁻¹

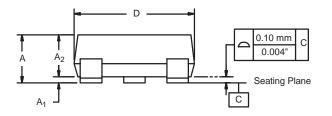
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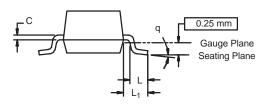
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SOT-23 (TO-236): 3-LEAD



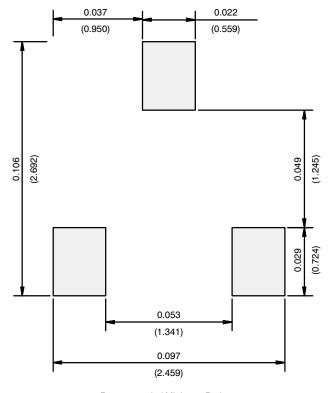




Dim	MILLIM	ETERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025	Ref	
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)



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